L Number	Hits	Search Text	DB	Time stamp
1	40146	electric\$3 same film same heat\$3	USPAT;	2003/08/13
		·	US-PGPUB;	12:44
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
2	1085	(electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide	US-PGPUB;	12:46
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
3	108	((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	12:47
		doped	EPO; JPO;	
İ		·	DERWENT;	
İ			IBM_TDB	
5	0	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
-	•	layer with metal adj oxide) and layer near2	US-PGPUB;	13:39
		doped) and substrate near2 insulat\$3) and	EPO; JPO;	10.00
		rare adj element	DERWENT;	
		raio aaj olement	IBM_TDB	
6	1	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
	•	layer with metal adj oxide) and layer near2	US-PGPUB;	12:49
		doped) and substrate near2 insulat\$3) and	EPO; JPO;	12.73
		rare with element	DERWENT;	
1		rate with element	IBM_TDB	
7	9	(((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
•	3	layer with metal adj oxide) and layer near2	US-PGPUB;	13:08
		doped) and substrate near2 insulat\$3 near3	EPO; JPO;	13:00
		electric\$3	DERWENT:	
			IBM_TDB	
4	46	(((electric\$3 same film same heat\$3) and	_	2003/08/13
•	40	layer with metal adj oxide) and layer near2	USPAT;	13:33
		doped) and substrate near2 insulat\$3	US-PGPUB;	13:33
		doped) and substrate nearz insulatas	EPO; JPO;	
			DERWENT;	
В	13	(((electric\$3 same film same heat\$3) and	IBM_TDB	2003/08/13
	13	layer with metal adj oxide) and layer near2	USPAT;	
			US-PGPUB;	13:21
		doped) and antimony and zinc	EPO; JPO;	
			DERWENT;	
	4	(//oleotric#2 same film same back#2)	IBM_TDB	2002/00/42
9	1	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	13:24
		doped) and antimony and zinc) and equal adj	EPO; JPO;	
		quantity	DERWENT;	
40	_	///	IBM_TDB	
10	0	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	13:26
		doped) and antimony and zinc) and flourine	EPO; JPO;	
			DERWENT;	
ļ			IBM_TDB	

11	698	"46" and flourine	USPAT;	2003/08/13
			US-PGPUB;	13:26
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
12	0	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	13:27
		doped) and substrate near2 insulat\$3) and	EPO; JPO;	
		flourine	DERWENT;	,
			IBM_TDB	
13	0	((((electric\$3 same film same heat\$3) and	USPAT:	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	13:28
		doped) and substrate near2 insulat\$3) and	EPO; JPO;	10.20
		density same "20" adj watt	DERWENT;	
		density same 20 auj watt	IBM_TDB	
14	27	///olootrio\$2 come film some boot\$2\ and		0000/00/40
	21	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	13:28
		doped) and substrate near2 insulat\$3) and	EPO; JPO;	
		density	DERWENT;	
			IBM_TDB	
15	11	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	13:28
		doped) and antimony and zinc) and density	EPO; JPO;	
		<u>-</u>	DERWENT;	
			IBM_TDB	
16	10	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	13:35
		doped) and substrate near2 insulat\$3) and	EPO; JPO;	10.00
		concentration same mol	DERWENT;	
			IBM_TDB	
17	4	((((electric\$3 same film same heat\$3) and	_	2003/08/13
• •	-	•	USPAT;	
		layer with metal adj oxide) and layer near2	US-PGPUB;	13:36
		doped) and substrate near2 insulat\$3) and	EPO; JPO;	
		concentration with mol	DERWENT;	
	_		IBM_TDB	
18	0	((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and rare adj	US-PGPUB;	13:39
		element with concentration	EPO; JPO;	
:			DERWENT;	
		·	IBM_TDB	
19	0	(electric\$3 same film same heat\$3) and rare	USPAT;	2003/08/13
		adj element with concentration	US-PGPUB;	13:39
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
21	3	((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
	•	layer with metal adj oxide) and rare adj3	1	
		element with concentration	US-PGPUB;	13:40
	ļ	element with concentration	EPO; JPO;	
		•	DERWENT;	
			IBM_TDB	

20	24	(electric\$3 same film same heat\$3) and rare adj3 element with concentration	USPAT; US-PGPUB; EPO; JPO;	2003/08/13 13:57
22	6	(electric\$3 same film same heat\$3) and monobutyl adj tin adj trichloride	DERWENT; IBM_TDB USPAT; US-PGPUB;	2003/08/13 14:29
23	277		EPO; JPO; DERWENT; IBM_TDB	2000/00/40
23	211	((electric\$3 same film same heat\$3) and layer with metal adj oxide) and annealing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 14:02
24	11	((((electric\$3 same film same heat\$3) and layer with metal adj oxide) and layer near2 doped) and substrate near2 insulat\$3) and annealing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 14:08
25	0	((((electric\$3 same film same heat\$3) and layer with metal adj oxide) and layer near2 doped) and substrate near2 insulat\$3) and annealing with pyrolysis	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 14:04
26	2	(((electric\$3 same film same heat\$3) and layer with metal adj oxide) and annealing) and annealing with pyrolysis	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/08/13 14:04
27	0	((((electric\$3 same film same heat\$3) and layer with metal adj oxide) and layer near2 doped) and substrate near2 insulat\$3) and metal adj oxide with annealing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 14:09
28	44	((electric\$3 same film same heat\$3) and layer with metal adj oxide) and metal adj oxide with annealing	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 14:14
29	19	((electric\$3 same film same heat\$3) and layer with metal adj oxide) and metal adj oxide with annealing with substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 14:16
30	6	(((electric\$3 same film same heat\$3) and layer with metal adjoxide) and metal adjoxide with annealing with substrate) and annealing with hour	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/13 14:17

31	45	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	14:29
		doped) and substrate near2 insulat\$3) and	EPO; JPO;	
		method	DERWENT;	
			IBM_TDB	
32	11	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	14:31
		doped) and substrate near2 insulat\$3) and	EPO; JPO;	
		method with manufacturing	DERWENT;	
			IBM_TDB	
33	31	(((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	14:31
		doped) and method with manufacturing	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
34	20	((((electric\$3 same film same heat\$3) and	USPAT;	2003/08/13
		layer with metal adj oxide) and layer near2	US-PGPUB;	14:31
		doped) and method with manufacturing) not	EPO; JPO;	
		(((((electric\$3 same film same heat\$3) and	DERWENT;	
		layer with metal adj oxide) and layer near2	IBM_TDB	
		doped) and substrate near2 insulat\$3) and		
		method with manufacturing)		

L Number	Hits	Search Text	DB	Time stamp
1	2	rare adj2 element with equal adj2	USPAT;	2003/08/13
-		concentration	US-PGPUB;	16:08
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
2	1376	rare adj2 element same concentration	USPAT;	2003/08/13
			US-PGPUB;	15:54
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
3	1376	rare adj2 elements same concentration	USPAT;	2003/08/13
			US-PGPUB;	15:54
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
4	822	rare adj2 elements with concentration	USPAT;	2003/08/13
-			US-PGPUB;	16:06
1			EPO; JPO;	10.00
1			DERWENT;	
			IBM_TDB	
5	0	rare adj2 elements with concentration	USPAT;	2003/08/13
		same equal	US-PGPUB;	15:55
			EPO; JPO;	13.33
			DERWENT;	
			IBM_TDB	
6	12	rare adj2 elements with concentration	USPAT;	2003/08/13
		same similar	US-PGPUB;	15:59
		Same Similar	EPO; JPO;	13.39
			DERWENT;	
			IBM_TDB	
7	47	rare adj2 elements with concentration	USPAT;	2003/08/13
-		same even	US-PGPUB:	15:59
		Same Gron	EPO; JPO;	13.39
			DERWENT;	
			IBM_TDB	
8	25	rare adj2 elements with concentration with	USPAT;	2003/08/13
-	-5	even	US-PGPUB;	16:05
			EPO; JPO;	10:05
			DERWENT;	
9	0	rare adj2 elements with concentration with	USPAT;	2003/08/13
-	5	match\$3	US-PGPUB;	16:05
			1	פטיסו
			EPO; JPO; DERWENT;	
			•	
10	o	rare adj2 elements with similar adj2	IBM_TDB	2003/00/40
	J	concentration	USPAT;	2003/08/13
		Concentration	US-PGPUB;	16:07
			EPO; JPO;	
			DERWENT; IBM_TDB	

11	2	rare adj2 element same equal adj2	USPAT;	2003/08/13
		concentration	US-PGPUB;	16:09
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
12	4	rare adj2 metal same equal adj2	USPAT;	2003/08/13
		concentration	US-PGPUB;	16:18
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
13	1	"19908688"	USPAT;	2003/08/13
			US-PGPUB;	16:19
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	